## Development Of Anode For Electrolysis Of (CH<sub>3</sub>)<sub>4</sub>NF·4HF Room-Temperature Molten Fluoride

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A room-temperature molten fluoride, (CH<sub>3</sub>)<sub>4</sub>NF·*m*HF melt  $(3.5 \le m \le 5.0)$ , is expected to be a useful electrolyte for electrochemical fluorination [1].  $(CF_3)_3N$  can be synthesized by electrochemical perfluorination of (CH<sub>3</sub>)<sub>4</sub>N<sup>+</sup> cation in the melt, and hence it will be a new process that can replace the Simons process, in which trimethylamine, (CH<sub>3</sub>)<sub>3</sub>N, dissolved in anhydrous HF is electrolyzed using the Ni anode [2, 3, 4]. However, a previous study revealed that the Ni anode is unfavorable in electrolysis for a long time in the (CH<sub>3</sub>)<sub>4</sub>NF<sup>4</sup>HF only melt, because an insulating film mainly composed of NiF2 is formed on the anode during electrolysis [5]. To develop a new electrolytic process using the  $(CH_3)_4NF \cdot mHF$  melt in an industrial scale, it is important to improve the Ni sheet anode as that covered with the film having a higher electric conductivity and a lower overvoltage for the fluoride ion discharge reaction.

It has been reported that the nickel based composite containing nickel oxide with the plural oxidation states gave a high electronic conductivity to the film and decreased the anode overvoltage in the (CH<sub>3</sub>)<sub>4</sub>NF·mHF melt [6]. LiNiO<sub>2</sub> and LaNiO<sub>3</sub> are considered to be useful film materials that are stable in the  $(CH_3)_4NF \cdot mHF$  melt. The LiNiO<sub>2</sub> and the LaNiO<sub>3</sub> coated Ni sheet anodes were prepared by a sol-gel coating method. The sol solution was prepared from La(CH<sub>3</sub>COO)<sub>3</sub>·1.5H<sub>2</sub>O), *i*-C<sub>3</sub>H<sub>7</sub>OLi (or polyvinlylpyrrolidone (PVP, Mw = 55000), CH<sub>3</sub>COOH, and i-C<sub>3</sub>H<sub>7</sub>OH. The sol solution was dip-coated on a Ni sheet, and was converted to a gel film by heating at 200°C for 20 minutes. Dip-coating and heat-treatment at 200°C were alternately performed with several times. After all coating processes, the gel film was heat-treated at 700 or 750°C for 2 hours in air. Fig. 1 shows the X-ray diffraction patterns of the samples. The XRD analysis revealed that LiNiO2 and LaNiO3 formed on the Ni substrate with oxides such as NiO and/or La2O3.

Fig. 2 shows the variations of the potential of the Ni sheet anode, the LiNiO<sub>2</sub> coated Ni sheet anode, and the LaNiO<sub>3</sub> coated Ni sheet anode with lapse of time during electrolysis at 20 mA cm<sup>-2</sup> in the (CH<sub>3</sub>)<sub>4</sub>NF·4HF melt. The potential on Ni anode rose up to 10 V for only 1 hour, whereas those on the LiNiO<sub>2</sub> and the LaNiO<sub>3</sub> coated Ni sheet anodes were kept at 6.54 and 5.04 V for 100 hours, respectively. These results indicate that LiNiO<sub>2</sub> and LaNiO<sub>3</sub> may give the electric conductivity to the Ni sheet anode during electrolysis.

The compositions of the evolved gas at the LiNiO<sub>2</sub> and LaNiO<sub>3</sub> coated Ni sheet anodes electrolyzed at 20 mA cm<sup>-2</sup> for 100 hours in the  $(CH_3)_4NF\cdot 4HF$  melt are shown in Table 1. The anode gas was composed of CF<sub>4</sub>, NF<sub>3</sub>, C<sub>2</sub>F<sub>6</sub>, CHF<sub>3</sub>, C<sub>2</sub>HF<sub>5</sub>, (CF<sub>3</sub>)<sub>3</sub>N, (CF<sub>2</sub>H)<sub>2</sub>NCF<sub>3</sub>, and (CF<sub>3</sub>)<sub>2</sub>NCF<sub>2</sub>H. The main constituents in the anode gas were CF<sub>4</sub> and (CF<sub>3</sub>)<sub>3</sub>N. The maximum ratio of (CF<sub>3</sub>)<sub>3</sub>N obtained was 25.4% when electrolysis using the sol-gel LiNiO<sub>2</sub> coated Ni sheet anode prepared by the procedure of dip-coating with five times was carried out at 20 mA cm<sup>-2</sup> in the (CH<sub>3</sub>)<sub>4</sub>NF·4HF melt for 100 hours.

These results suggest that the electrolytic production of  $(CF_3)_3N$  from  $(CH_3)_4NF\cdot 4HF$  melt using the LiNiO<sub>2</sub> and

 $LaNiO_3$  coated Ni sheet anodes is a useful process because the electrolytic conductivity of these oxide films on the anode is kept higher during electrolysis.



Fig.1 X-ray diffraction patterns of (a) the sol-gel LiNiO<sub>2</sub> coated Ni sheet and (b) the sol-gel LaNiO<sub>3</sub> coated Ni sheet prepared by the procedure of dip-coating with five times. ( $\bigcirc$ ) LiNiO<sub>2</sub>, ( $\bigoplus$ ) Li<sub>2</sub>CO<sub>3</sub>, ( $\triangle$ ) LaNiO<sub>3</sub>, ( $\blacktriangle$ ) La<sub>2</sub>O<sub>3</sub>, ( $\square$ ) Ni, and ( $\blacksquare$ ) NiO.



The sol-gel LiNiO<sub>2</sub> coated Ni sheet anode prepared by the procedure of dip-coating with five times, and (c) the sol-gel LaNiO<sub>3</sub> coated Ni sheet prepared by the procedure of dip-coating with five times during electrolysis at 20 mA cm<sup>-2</sup> in the (CH<sub>3</sub>)<sub>4</sub>NF-4HF melt at room temperature.

Table 1 The compositions of the anode gas electrolyzed at 20 mA cm<sup>-2</sup> for 100 h in the  $(CH_3)_4NF$ ·4HF melt at room temperature.

Material (Number of times of the dip coating process)	the composition of evolved gas / $\%$						
	$CF_4$	$NF_3$	$C_2F_6$	CHF <sub>3</sub>	$C_2HF_5$	Р	(CF <sub>3</sub> ) <sub>3</sub> N
Sol-gel LiNiO2 coated Ni sheet							
three times	53.9	2.0	5.5	7.3	1.5	8.0	21.8
five times	57.1	3.1	0.6	5.8	6.8	1.2	25.4
Sol-gel LaNiO3 coated Ni sheet							
three times	70.1	4.2	5.6	1.8	8.5	3.0	6.8
five times	60.8	3.4	4.7	1.5	8.6	6.0	15.1

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